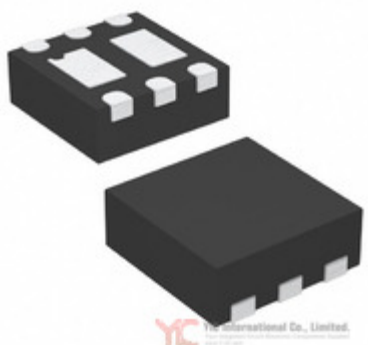

	<p>SIA850DJ-T1-GE3</p>
	<p>Hersteller-Teilenummer: SIA850DJ-T1-GE3</p>
	<p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p>
	<p>Teil der Beschreibung: MOSFET N-CH 190V 0.95A SC70-6</p>
	<p>Datenblätter:  SIA850DJ-T1-GE3.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>


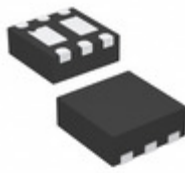
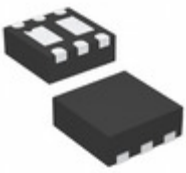
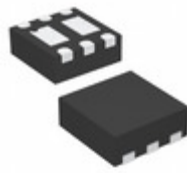
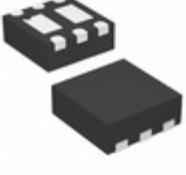
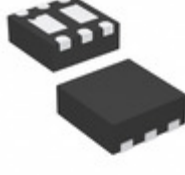
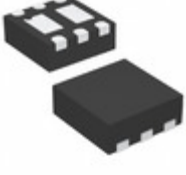
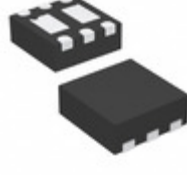
Spezifikationen

Teilenummer	SIA850DJ-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 190V 0.95A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	1.4V @ 250µA
Vgs (Max)	±16V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Dual
Serie	LITTLE FOOT®
Rds On (Max) @ Id, Vgs	3.8 Ohm @ 360mA, 4.5V
Verlustleistung (max)	1.9W (Ta), 7W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	PowerPAK® SC-70-6 Dual
Andere Namen	SIA850DJ-T1-GE3-ND
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Eingabekapazität (Ciss) (Max) @ Vds	90pF @ 100V
Gate Charge (Qg) (Max) @ Vgs	4.5nC @ 10V
Typ FET	N-Channel
FET-Merkmal	Schottky Diode (Isolated)
Antriebsspannung (Max Rds On, Min Rds On)	1.8V, 4.5V
Drain-Source-Spannung (Vdss)	190V
detaillierte Beschreibung	N-Channel 190V 950mA (Tc) 1.9W (Ta), 7W (Tc)
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	950mA (Tc)

SIA850DJ-T1-GE3 Electronic Components ist ein 100% neues Original von YIC Distributor, SIA850DJ-T1-GE3-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, SIA850DJ-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.

RFQ SIA850DJ-T1-GE3 E-Mail: Info@Y-IC.com

Sie können auch interessiert

<p>sein:</p>  <p>SIA906EDJ-T1-E3 VISHAY VISHAY QFN-6</p>	 <p>SIA814DJ-T1-GE3 Vishay Siliconix MOSFET N-CH 30V 4.5A SC70-6</p>	 <p>SIA813DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 4.5A SC70-6</p>	 <p>SIA906EDJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 4.5A SC70-6</p>
 <p>SIA817EDJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 4.5A SC-70-6</p>	 <p>SIA817EDJ-T1-GE3 Vishay Siliconix MOSFET P-CH 30V 4.5A SC-70-6</p>	 <p>SIA814DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 4.5A SC70-6</p>	 <p>SIA906EDJ-T1-GE3 Vishay Siliconix MOSFET 2N-CH 20V 4.5A SC70-6</p>

Verwandtes Hot-Keyword

Mehr

SIA850DJ-T1-GE3 Electro-Films (EFI) / SIA850DJ-T1-GE3 Datenblatt Vishay	SIA850DJ-T1-GE3-Datenblätter	SIA850DJ-T1-GE3 PDF	Electro-Films (EFI) / Vishay SIA850DJ-T1-GE3
SIA850DJ-T1-GE3 Electronic	SIA850DJ-T1-GE3-Komponenten	SIA850DJ-T1-GE3-Verteiler	SIA850DJ-T1-GE3-Bild
SIA850DJ-T1-GE3 Preis	SIA850DJ-T1-GE3 Hersteller	SIA850DJ-T1-GE3 Bild	SIA850DJ-T1-GE3 Aktie
SIA850DJ-T1-GE3 Neu	SIA850DJ-T1-GE3 Original	SIA850DJ-T1-GE3 garantiert	SIA850DJ-T1-GE3 RFQ
			SIA850DJ-T1-GE3 Inventar
			SIA850DJ-T1-GE3 Online bestellen

Contact us: Info@Y-IC.com

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